

COS/MOS INTEGRATED CIRCUIT

4502B

HCC/HCF 4502B

STROBED HEX INVERTER/BUFFER

- 2 TTL-LOAD OUTPUT DRIVE CAPABILITY
- 3-STATE OUTPUTS
- COMMON OUTPUT-DISABLE CONTROL
- INHIBIT CONTROL
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- 5V, 10V, AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100 nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD No. 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

The **HCC 4502B** (extended temperature range) and **HCF 4502B** (intermediate temperature range) are monolithic integrated circuit, available in 16-lead dual in-line plastic or ceramic package, ceramic flat package and plastic micropackage. The **HCC/HCF 4502B** consists of six inverter-buffers with 3-state outputs. A logic "1" on the OUTPUT DISABLE input produces a high-impedance state in all six outputs. This feature permits common bussing of the outputs, thus simplifying system design. A logic "1" on the INHIBIT input switches all six outputs to logic "0" if the OUTPUT DISABLE input is a logic "0". This device is capable of driving two standard TTL loads, which is equivalent to six times the JEDEC "B" series I_{OL} standard.

ABSOLUTE MAXIMUM RATINGS

V_{DD} *	Supply voltage: HCC types HCF types	-0.5 to 20 -0.5 to 18	V V
V_i	Input voltage	-0.5 to $V_{DD} + 0.5$	V
I_i	DC input current (any one input)	± 10	mA
P_{tot}	Total power dissipation (per package) Dissipation per output transistor for T_{op} = full package-temperature range	200 100	mW mW
T_{op}	Operating temperature: HCC types HCF types	-55 to 125 -40 to 85	°C °C
T_{stg}	Storage temperature	-65 to 150	°C

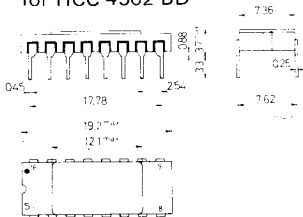
* All voltage values are referred to V_{SS} pin voltage

ORDERING NUMBERS:

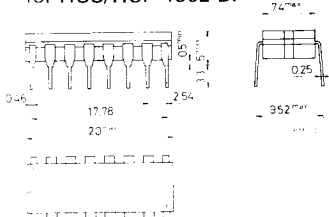
- HCC 4502 BD for dual in-line ceramic package
- HCC 4502 BF for dual in-line ceramic package, frit seal
- HCC 4502 BK for ceramic flat package
- HCF 4502 BE for dual in-line plastic package
- HCF 4502 BF for dual in-line ceramic package, frit seal
- HCF 4502 BM for plastic micropackage

MECHANICAL DATA (dimensions in mm)

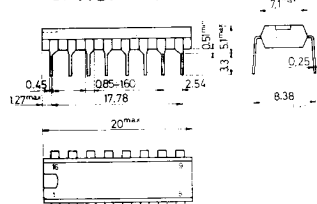
Dual in-line ceramic package for HCC 4502 BD



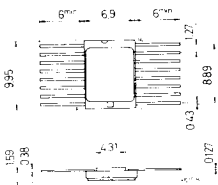
Dual in-line ceramic package for HCC/HCF 4502 BF



Dual in-line plastic package for HCF 4502 BE



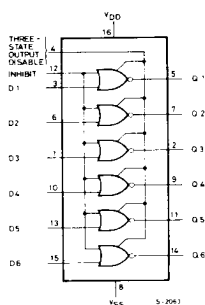
Ceramic flat package for HCC 4502 BK



Plastic micropackage for HCF 4502 BM



CONNECTION DIAGRAM



TRUTH TABLE

DISABLE	INHIBIT	Dn	Qn
0	0	0	1
0	0	1	0
0	1	X	0
1	X	X	Z

X = Don't Care
 Z = High Impedance
 Logic 1 = High
 Logic 0 = Low

RECOMMENDED OPERATING CONDITIONS

V_{DD}	Supply voltage: HCC types HCF types	3 to 18 V	V
V_I	Input voltage	3 to 15 V	V
T_{op}	Operating temperature: HCC types HCF types	0 to V_{DD} -55 to 125 °C -40 to 85 °C	°C

STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Parameter		Test conditions				Values						Unit		
		V _I (V)	V _O (V)	I _O (μA)	V _{DD} (V)	T _{Low} *		25 °C			T _{High} *			
						Min.	Max.	Min.	Typ.	Max.	Min.		Max.	
I _L	Quiescent current	HCC types	0/ 5			5		1		0.02	1		30	μA
			0/10			10		2		0.02	2		60	
			0/15			15		4		0.02	4		120	
	0/20			20		20		0.04	20		600			
	HCF types	0/ 5			5		4		0.02	4		30		
		0/10			10		8		0.02	8		60		
0/15				15		16		0.02	16		120			
V _{OH}	Output high voltage	0/ 5		< 1	5	4.95		4.95			4.95		V	
		0/10		< 1	10	9.95		9.95			9.95			
		0/15		< 1	15	14.95		14.95			14.95			
V _{OL}	Output low voltage	5/0		< 1	5		0.05			0.05		0.05	V	
		10/0		< 1	10		0.05			0.05		0.05		
		15/0		< 1	15		0.05			0.05		0.05		
V _{IH}	Input high voltage		0.5/4.5	< 1	5	3.5		3.5			3.5		V	
			1/9	< 1	10	7		7			7			
			1.5/13.5	< 1	15	11		11			11			
V _{IL}	Input low voltage		4.5/0.5	< 1	5		1.5			1.5		1.5	V	
			9/1	< 1	10		3			3		3		
			13.5/1.5	< 1	15		4			4		4		
I _{OH}	Output drive current	HCC types	0/ 5	2.5		5	-2		-1.6	-3.2		-1.15	mA	
			0/ 5	4.6		5	-0.64		-0.51	-1		-0.36		
			0/10	9.5		10	-1.6		-1.3	-2.6		-0.9		
		0/15	13.5		15	-4.2		-3.4	-6.8		-2.4			
		HCF types	0/ 5	2.5		5	-1.53		-1.36	-3.2		-1.1		
			0/ 5	4.6		5	-0.52		-0.44	-1		-0.36		
0/10	9.5			10	-1.3		-1.1	-2.6		-0.9				
0/15	13.5		15	-3.6		-3.0	-6.8		-2.4					
I _{OL}	Output sink current	HCC types	0/ 5	0.4		5	3.84		3.06	6		2.10	mA	
			0/10	0.5		10	9.6		7.8	15.6		5.4		
			0/15	1.5		15	25.2		20.4	40.8		14.4		
		HCF types	0/ 5	0.4		5	3.11		2.6	6		2.10		
			0/10	0.5		10	7.05		6.63	15.6		5.61		
			0/15	1.5		15	20.4		17.3	40.8		14.2		
I _{IH} , I _{IL}	Input leakage current	HCC types	0/18			18			±0.1	±10 ⁻⁵	±0.1		± 1	μA
		HCF types	0/15		Any input	15			±0.3	±10 ⁻⁵	±0.3		± 1	
I _{OH} , I _{OL}	3-state output	HCC types	0/18			18			±0.4	±10 ⁻⁴	±0.4		± 12	μA
		HCF types	0/15			15			±1.0	±10 ⁻⁴	±1.0		±7.5	
C _I	Input capacitance			Any input					5	7.5			pF	

* T_{Low} = - 55 °C for HCC device; -40 °C for HCF device.

* T_{High} = +125 °C for HCC device; +85 °C for HCF device.

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} = 5V
2V min. with V_{DD} = 10V
2.5V min. with V_{DD} = 15V

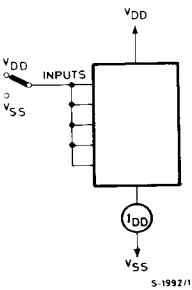
HCC/HCF 4502B

DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$, typical temperature coefficient for all V_{DD} values is $0.3\%/^{\circ}\text{C}$, all input rise and fall times = 20 ns)

Parameter	Test conditions	Values			Unit	
		V_{DD} (V)	Min.	Typ.		Max.
t_{PHL} Data or inhibit delay time		5		135	270	ns
		10		60	120	
		15		40	80	
t_{PLH} Data or inhibit delay time		5		190	380	ns
		10		90	180	
		15		65	30	
t_{PHZ} Disable delay time (output high to high impedance)		5		60	120	ns
		10		40	80	
		15		30	60	
t_{PZH} Disable delay time (high impedance to output high)		5		110	220	ns
		10		50	100	
		15		40	80	
t_{PLZ} Disable delay time (output low to high impedance)		5		125	250	ns
		10		65	130	
		15		55	110	
t_{PZL} Disable delay time (high impedance to output low)		5		125	250	ns
		10		55	110	
		15		40	80	
t_{TLH} Transition time		5		100	200	ns
		10		50	100	
		15		40	80	
t_{THL} Transition time		5		60	120	ns
		10		30	60	
		15		20	40	

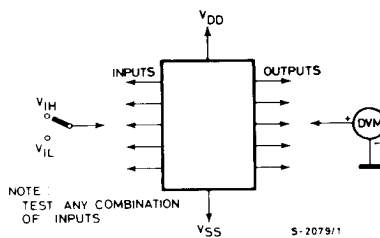
TEST CIRCUIT

Quiescent device current



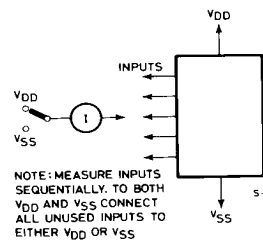
S-1992/1

Input voltage



S-2079/1

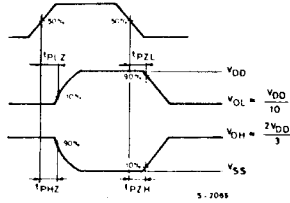
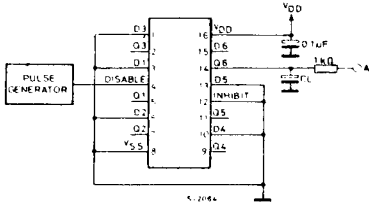
Input leakage current



NOTE: MEASURE INPUTS SEQUENTIALLY. TO BOTH V_{DD} AND V_{SS} CONNECT ALL UNUSED INPUTS TO EITHER V_{DD} OR V_{SS}

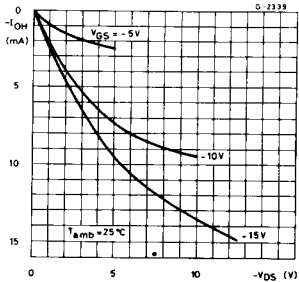
S-199

Test circuit and waveforms
disable delay time

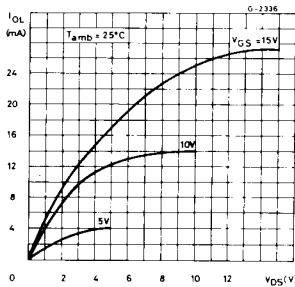


TEST CONDITION		
Test	Pin 15	Point A
tPHZ	V _{SS}	V _{SS}
tPLZ	V _{DD}	V _{DD}
tPZL	V _{DD}	V _{DD}
tPZH	V _{SS}	V _{SS}

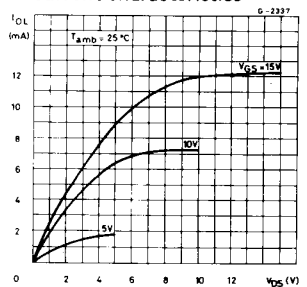
Minimum output high(source) current characteristics



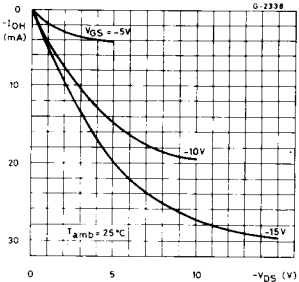
Typical output low (sink) current



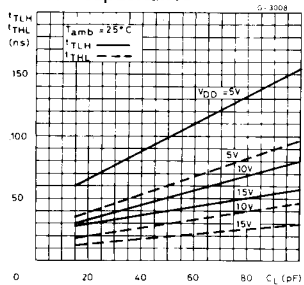
Minimum output low (sink) current characteristics



Typical output high (source) current characteristics



Typical transition time vs. load capacitance



Typical propagation delay time vs. load capacitance

